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Proposal for a two-qubit quantum phase gate for quantum photonic integrated circuits

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We propose a protocol for a two-qubit quantum phase gate based upon the reflection of photon pulses from a quantum dot in a cavity. Depending on the state of the quantum dot the reflected photons acquire a conditional phase shift. The key ingredient is the ultrafast control of the quantum dot energies by electric fields, which allows for tuning the exciton and biexciton successively into resonance with the cavity mode. The complete dynamics of the gate are simulated, revealing a fidelity of about 0.9. The proposed scheme uses position coding and is therefore well suited to the implementation in an integrated photonic quantum processor.

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I. INTRODUCTION

During the last decade, fast progress in theory and experiments has brought information processing using quantum states within reach [1]. Based on fundamental properties of quantum mechanics, communication protocols enable secure information transfer, and quantum computation schemes should be able to outperform classical systems for specific computational tasks [2]. The basic building blocks are quantum systems, which should allow for local storage of quantum bits (qubits) as well as qubit processing via quantum gates [3,4].

Photonic quantum technologies are expected to play a key role in implementing quantum information systems owing to fast, reliable, and coherent transport of quantum information via single photons [5]. The challenge in photonics is to realize the nonlinear photon-photon interaction, which is crucial for nontrivial two-qubit quantum gates. Since the typical optical nonlinearities are very weak at the single-photon level, various material systems are in the focus of research to mediate the required interactions between photons. Atoms and superconducting circuits provide a versatile platform for quantum information processing [1,6,7]. However, large-scale quantum networks will require compact nodes and photon exchange through fibers and therefore operations at near-infrared wavelengths. For this reason, solid-state quantum dots (QDs) have a key advantage in terms of optical transitions at the telecommunication wavelength. Furthermore, they offer the prospect of integration, scalability, and ultrafast control using electrical pulses [8] and acoustic pulses [9,10]. The possibility of embedding QDs in photonic crystal cavities provides an additional benefit as it enhances the light-matter interaction down to the single-photon level. These QD-cavity systems can be combined with Stark tuning of the exciton energies, allowing the control of exciton-photon interaction via the spectral mismatch [11–14]. However, even though QDs are often called artificial atoms, their specific internal level structure prevents direct translation of a variety of proposals based on Λ-type atomic systems to the solid state. Indeed, while the radiative recombination of QD excitons has been shown to enable applications as nonclassical light sources [15–20], only proof-of-principle experiments towards photonic quantum gates have been reported [21]. Moreover, many of the proposed quantum gate schemes based on QDs (e.g., Ref. [22–24]) rely on interaction with the spin degree of freedom and therefore on polarization coding, which is not adapted to integration in waveguide circuits due to the anisotropic character of radiative transitions in QDs and the poor control of birefringence in waveguides. Here, we propose a scheme where the qubits are coded in the position, rather than the polarization, of single photons. It relies on ultrafast electrical control of the QD-cavity interaction and is well adapted to an implementation in an integrated quantum photonic circuit.

This paper is organized as follows. We sketch the quantum gate protocol in Sec. II. The simulations of the dynamics are presented in Sec. III. The paper is closed with a summary and conclusions in Sec. IV.

II. PHASE GATE PROTOCOL

The big challenge in quantum information processing is that photons do not interact, while interaction is a crucial requirement for the basic building blocks of quantum computers such as quantum gates. In order to overcome this problem, one may think to transfer the photonic qubit into a material qubit. In the present case we will focus on the exciton and on the biexciton in a QD. A crucial requirement is the efficient transfer between a photon and the exciton, which can be enhanced by placing the QD in a cavity. The potentially high efficiency of the single-photon absorption [14] opens the way to using the intrinsic nonlinearity of solid-state systems for the quantum control of photonic qubits.

At the heart of the proposed two-qubit quantum gate is the phase change upon reflection of a photon on a cavity-QD system [25,26], depending on the state of the QD. The cavity-QD coupling is set to operate on the edge between the strong- and weak-coupling regimes. A fundamental difference between our proposal and previous proposals based on cavity quantum electrodynamics (e.g., Ref. [25]) is that it does not rely on two metastable ground states, which is typical for Λ-type systems. Because in QDs such metastable states can only be based on electron and hole spins, their manipulation involves the use of the polarization degree of freedom of the photon, which, as mentioned above, is not suited for integration. Instead, our proposal relies on transitions between different exciton levels with fixed polarization selection rules.

We treat the QD as a three-level system, considering the exciton transition with frequency $\omega_X$ and the biexciton transition with $\omega_{XX} = \omega_X - \Delta$, where $\Delta$ is the biexciton binding energy originating from the Coulomb interaction. It is
different waveguides. The photon in channel enter the gate via two channels consisting, for example, of two constant

Figure 1(a) shows the sketch of the quantum gate. The photons and the corresponding relevant level structures are shown in the cavity mode. Bearing this in mind, the complete work either the exciton or the biexciton transition is resonant with over a region larger than the biexciton binding energy so that confined Stark effect, which is used to tune the QD resonances is used to spatially separate the input and output ports. The only if photon 1 enters the gate in channel and for the cavity mode XX with a bare cavity mode [25,26].

conditional structure the biexciton transition conditionally depends on the typically about 2–4 meV in InAs/GaAs QDs. In this three-level structure the biexciton resonance of the QD are rapidly (described in Ref. [14]. The Hamiltonian describing the system dynamics in a rotating frame reads (\(\hbar = 1\))

\[
H = \Delta_x a^\dagger a + (\Delta_{\omega_1} + i\gamma)a^\dagger a + ig(a^\dagger a^\dagger - a^\dagger a) + i\sqrt{\frac{\Delta\omega}{2\pi}} \sum_{k=1}^{N} (a^\dagger b_k - ab_k^\dagger) + \sum_{k=1}^{N} \Delta_k b_k^\dagger b_k.
\]

where \(a^\dagger (a), a^\dagger (a), b_k^\dagger (b_k)\) are the creation (annihilation) operators for the cavity mode, the two-level system, and the continuum modes of the waveguide. The values \(\Delta_{\omega_1}(t), \Delta_{\omega_2},\) and \(\Delta_k\) are the energy detunings of the two-level transition (time dependent due to the dynamic Stark shift), the cavity, and the output mode k from the rotating frame. We assume that in the output field only modes within a finite bandwidth \(\omega_1 - \omega_2, \omega_1 + \omega_2\) have non-negligible contributions to the dynamics. Finally, \(\gamma\) is the decay rate of the quantum dot exciton, \(g\) is the coupling between the cavity and exciton, and \(\kappa\) denotes the cavity decay rate into the waveguide.

The combination of the cavity-continuum interaction and the wave-function approach [28] allows investigating the dynamics of arbitrarily shaped single-photon pulses interacting with the cavity [25,28]. We expand the wave function of the system in all possible states, limiting ourselves to the case of a single excitation since photons arrive successively:

\[
|\Psi\rangle = \alpha |\epsilon\rangle|0\rangle + \beta |g\rangle|1\rangle|\text{vac}\rangle + |g\rangle|0\rangle \sum_{k=1}^{N} \beta_k b_k^\dagger |\text{vac}\rangle.
\]

The state \(|\text{vac}\rangle\) denotes the vacuum state of all modes in the quasicontinuum of the waveguide. The modulus square of the...
amplitude $\beta$ describes the probability to find one photon in the cavity, and $\beta_k$ are the amplitudes for the modes of the quasicontinuum. The amplitude $\alpha$ describes the dynamics of the excited state of the quantum dot. Later we will use $\alpha_X$ and $\alpha_{XX}$ for the exciton and biexciton states. All state amplitudes satisfy, in the case $\gamma = 0$,

$$|\alpha|^2 + |\beta|^2 + \sum_{k=1}^{N} |\beta_k|^2 = 1. \quad (4)$$

Plugging this wave-function expansion into the time-dependent Schrödinger equation $i\hbar \partial |\Psi(t)\rangle = H |\Psi(t)\rangle$ yields a system of coupled differential equations, which govern the time evolution of the state amplitudes:

$$\dot{\alpha} = g\beta + [-i\Delta_{o\alpha}(t) - \gamma]|\alpha|, \quad (5)$$

$$\dot{\beta} = -i\Delta_c\beta - g\alpha + \kappa' \sum_{j=1}^{N} \beta_k, \quad (6)$$

$$\dot{\beta}_k = -i\Delta_k\beta_k - \kappa'\beta, \quad (7)$$

where $\kappa' = \frac{\kappa}{\sqrt{2\pi}}$.

The coupled quantum dot-cavity system interacts with single-photon pulses. After a time $T$ such that the time evolution is completed, the pulse shape $f_{out}(t)$ and the output mode amplitudes are connected via the discrete inverse Fourier transform:

$$f_{out}(t) = \frac{1}{\sqrt{2\pi}} \sum_{k=1}^{N} \beta_k(T) e^{-i\omega_k(t-T)}. \quad (8)$$

Using the Fourier transform, one can also define arbitrarily shaped single-photon input pulses as initial condition $\beta_k(0)$. We are focusing on Gaussian single-photon wave packets $f_{in}(t) \propto e^{-|t|^2/\sigma^2}$.

As elaborated in a previous work [14], we have shown that the quantum state transfer from a photon to an exciton can be accomplished with an efficiency reaching 0.97 by using a QD in a microcavity operated on the edge between the strong- and weak-coupling regimes, i.e., $g \approx \kappa$, and by setting the temporal length $w$ of the incident Gaussian single-photon pulse to about $1/g$.

The simulated dynamics are presented in Fig. 2. The inner-cavity dynamics are displayed in Fig. 2(a) for an input state $\Psi_{in} = |a\rangle_1 |b\rangle_2$. After a given time the incident photon in channel $a$ enters the cavity and is absorbed by the quantum dot. The absorption is close to 1; however, a small imperfection arises from the pulse-shape mismatch between the incident Gaussian single photon and the initial emitter profile, which is not perfectly symmetric in the time domain [14]. During step 2 of the protocol the QD is frozen in its excited state by ultrafast electric field tuning. Finally, during step 3, the photon is released again into the cavity mode. Figure 2(b) illustrates one of two different scenarios in the second step of the protocol corresponding to the input state $\Psi_{in} = |a\rangle_1 |a\rangle_2$. A first photon in channel $a$ has been absorbed and a second photon in channel $a$ will interact with the biexciton transition $|\alpha_{XX}\rangle^2$ of the QD. It is released immediately after absorption. Finally, Fig. 2(c) shows the dynamics for the input state $\Psi_{in} = |b\rangle_1 |a\rangle_2$. Since the first photon was in channel $b$, the second photon (channel $a$) cannot address the biexciton transition and thus interacts with a bare cavity mode. In this case the photon will acquire a $\pi$ phase shift [Fig. 3(a)], which is robust against all parameter settings. During the gate operation it appears that the first photon in channel $a$ will acquire an additional phase shift $e^{i\Phi}$ after step 3 due to the imperfect absorption. This can be corrected by adding a phase modulator in the $b$ path synchronized with the

FIG. 2. (Color online) Temporal dynamics for photons in channel $a$. (a) Evolution of the exciton population $|\alpha_X|^2$ (black line) and the cavity $|\beta|^2$ (red (gray) line) for $|a\rangle_1 |b\rangle_2$ as input state vs dimensionless time $gt$. The biexciton population $|\alpha_{XX}|^2$ (dashed line) and cavity population (red solid line) corresponding to (b) $\Psi_{in} = |a\rangle_1 |a\rangle_2$ and (c) $\Psi_{in} = |b\rangle_1 |a\rangle_2$.

FIG. 3. (Color online) Performance of the phase gate. (a) Phase $\Phi$ vs dimensionless time $gt$ and (b) fidelity $F$ vs QD decay $\gamma/\kappa$ (dimensionless) for the different input states.
first step of the protocol. Furthermore, temporal reordering of a-channel photons by the gate can be compensated by an appropriate delay line for b-channel photons.

The fidelity $F$ of the gate operation is limited by the pulse-shape mismatch between the injected $f_{in}(t)$ and processed photon $f_{out}(t)$ and can be calculated using $F \propto \int |f_{in}(t) - f_{out}(t)| dt$, where $\tau$ is the time delay acquired during the qubit processing. The gate performance is illustrated in Fig. 3(b), which displays the fidelities for each input case versus the ratio between exciton decay $\gamma$ and cavity decay rate $\kappa = g$. The limiting process is given by the input state $\Psi_{in} = |a\rangle_1 |a\rangle_2$. The fidelity for this configuration can be determined to be $F = 0.89$ in the case $\gamma = 0$. It is also this state which suffers most from the quantum dot decay, which is natural because of the subsequent absorption and reemission of two photons. Typical QD lifetimes are in the range of a few nanoseconds, while the cavity lifetime is typically a few picoseconds, implying that the condition $\gamma \ll \kappa$ is well fulfilled, and fidelities above 0.85 can be expected for realistic parameters. However, active pulse-shaping techniques by electric fields [14] combined with ultrafast phase modulators can be used, in principle, to increase the fidelity. In addition dynamically tuned cavities can be used to generate the required photon pulses and to perform the gate operation. This would increase the absorption $|29,30\rangle$ during step 1 to arbitrarily close to 1 and thus improve the gate fidelity.

Finally, we want to compare the experimental state of the art with the requirements of the present proposal. First and most important, the coherence time of the QD exciton at low temperatures can be as long as 700 ps [31], which well exceeds the required operation time of the present proposal. The electrical control of QDs in photonic crystal cavities has been realized by several research teams [11–13]. The main constraint for the realization of the dynamic control is the fast change of the electric field. Typical time scales of the QD decay in a cavity are about 100 ps, which requires an electrical bandwidth of the ultrafast electrical tuning of about 10 GHz, which is feasible but challenging in semiconductor systems. However, increasing the $Q$ factor of the cavity and considering QDs with a smaller $g$ allow for slowing down the dynamics and thus the required speed of the electrical control. The coupling of QDs to waveguides [32–34] and combined waveguide-cavity-QD systems [35] pave the way towards on-chip integration. The problem of birefringence in waveguides, which gives rise to complications for the integration in the case of polarization coding, is circumvented by means of position coding in the present proposal. Finally, the gate favors QDs with a nonzero fine-structure splitting of the excitons, which makes the correction $|18,36–38\rangle$ for this naturally appearing feature in QDs unnecessary.

IV. SUMMARY AND CONCLUSIONS

In summary, we have theoretically shown that the dynamic electrical control of a coupled QD-cavity system can be an efficient tool to engineer the light-matter interaction in the solid state. Our simulations show that this external manipulation can be used as a basis of a cavity-assisted quantum phase gate. The simulations reveal fidelities up to 0.9. The present proposal illustrates a controlled solid-state quantum system suited to be implemented in quantum photonic integrated circuits.

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